Diode Semiconductor Device - Page 1 of 1



drawing, etc.;

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Inclosure Mater	ial:
Glass	
Overall Length:	
Between 0.120 i	nches and 0.200 inches
Terminal Lengt	h:
0.500 inches	
Overall Diamete	er:
Between 0.060 i	nches and 0.090 inches
End Application	1:
Radio set, an/aro	x-18
Joint Electronic	Device Engineering Council/jedec/case Outline Designation:
Do-35	
Mounting Methe	od:
Terminal	
Semiconductor	Material:
Silicon	
Voltage Rating	In Volts Per Characteristic:
30.0 reverse vol	tage, average
Current Rating	Per Characteristic:
100.00 milliampe	eres source cutoff current preset
Maximum Oper	ating Tempurature Per Measurement Point:
125.0 degrees c	elsius junction
Test Data Docu	ment:
37695-647916 d	rawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer of
excludes any sp	ecification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type	And Quantity:
2 uninsulated wi	re lead
Shelf Life:	
N/a	
Unit Of Measure	e:
Demilitarization	:
Yes - demil/mli	
Fiig:	
A110a0	